Chiral magnetization textures stabilized by the Dzyaloshinskii-Moriya interaction during spin-orbit torque switching

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Chiral magnetization textures stabilized by the Dzyaloshinskii-Moriya interaction during spin-orbit torque switching

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We study the effect of the Dzyaloshinskii-Moriya interaction (DMI) on current-induced magnetic switching of a perpendicularly magnetized heavy-metal/ferromagnet/oxide trilayer both experimentally and through micromagnetic simulations. We report the generation of stable helical magnetization stripes for a sufficiently large DMI strength in the switching region, giving rise to intermediate states in the magnetization and confirming the essential role of the DMI on switching processes. We compare the simulation and experimental results to a macrospin model, showing the need for a micromagnetic approach. The influence of the temperature on the switching is also discussed. © 2014 AIP Publishing LLC. [http://dx.doi.org/10.1063/1.4867199]

It has been recently reported that the magnetization of perpendicular anisotropy heavy-metal/ferromagnet/oxide multilayers can be switched by in-plane injected current.1–5 This current induced switching has been attributed to so-called spin-orbit torques (SOTs) due to the spin-Hall effect (SHE)2–6 and to the Rashba effect,1,7–9 arising from spin-orbit coupling and broken inversion symmetry at the heavy-metal/ferromagnet interface. SOT switching has been studied theoretically6 and experimentally for Pt/Co/AlOx,1,3,7,10 Pt/Co/Pt,11 Ta/CoFeB/MgO,12 Pt/CoFe/MgO,5 and Ta/CoFe/MgO5 nanodots and nanostrips5,3,14 and may provide an efficient means to operate ferromagnetic memories15 such as SOT-based magnetic random access memories (SOT-MRAM) or racetrack memories.16 More recently, it has been shown that the Dzyaloshinskii-Moriya interaction (DMI) plays an important role in domain wall (DW) motion in such materials5,17–20 and may also be important in SOT switching.21

The SHE in the heavy metal layer deflects electrons with opposite spin in opposite directions, giving rise to a spin current that is injected into the ferromagnet, exerting a Slonczewski-like torque on the ferromagnet magnetization.3 The Rashba effect leads to a current-induced effective field parallel to the interface and transverse to the current and may additionally generate a Slonczewski-like torque. On the other hand, the DMI17–19 acts as an antisymmetric exchange interaction that promotes non-uniform magnetization in materials where inversion symmetry is broken due to lack of a lattice inversion center or due to the presence of surfaces or interfaces. The DMI directly competes with the exchange interaction (which tends to maintain the magnetization uniform) and when strong enough encourages the formation of rotational magnetic textures of definite chirality, such as chiral DWs,20 skyrmions,22 or spin helixes.23 SOT switching has usually been interpreted in the framework of a simple macrospin model, but recent micromagnetic simulations show that the reversal process is in fact highly non-uniform.24 In this case, it can be anticipated that strong DMI should significantly impact the inhomogeneous reversal process, necessitating a full micromagnetic model to provide meaningful interpretation of experiments.

Here, we study SOT switching experimentally and through a micromagnetic model that includes the Slonczewski-like and field-like SOTs, DMI, and finite temperature. Although the Slonczewski-like SOT drives magnetization switching, the field-like SOT and DMI play key roles in the switching process and switching efficiency. We show that strong DMI leads to metastable chiral intermediate states and introduces a stochastic nature to the switching process. A strong field-like torque, by contrast, promotes quasi-uniform, deterministic switching and significantly lowers the switching threshold. 

Experiments focus on perpendicular anisotropy Ta(3 nm)/Pt(3 nm)/CoFe(0.6 nm)/MgO(1.8 nm)/Ta(2 nm) and Ta(5 nm)/CoFe(0.6 nm)/MgO(1.8 nm)/Ta(2 nm) films sputter-deposited onto Si/SiO2 substrates and patterned into 1200-nm-wide Hall crosses (Fig. 1(a)). See Ref. 5 for sample details. Strong Slonczewski-like torques have been observed in Pt/CoFe and Ta/CoFe stacks5 and attributed to large spin Hall angles2,3 in Pt and Ta. At the same time, experiments indicate5,25 Pt/CoFe exhibits strong DMI and a relatively weak field-like SOT, while Ta/CoFe exhibits weak DMI and a strong field-like SOT. These materials thus provide an opportunity to independently examine the roles of these effects on SOT switching.

The Slonczewski-like torque in heavy-metal/ferromagnet bilayers is described by an effective field \(\mathbf{B}_{\text{SL}} = \mathbf{m} \times (\mathbf{\hat{z}} \times \mathbf{J})\), where \(\mathbf{m} = \mathbf{M}/M_S\) is the normalized magnetization, \(\mathbf{\hat{z}}\) is film normal, and \(\mathbf{J}\) is the current density. A small in-plane field \(\mathbf{B}_x\) along the current axis (Fig. 1(b)) enables current-induced switching of the z-component of magnetization between \(m_z = \pm 1\). Figures 1(c) and 1(d) show current-induced switching in Pt/CoFe and Ta/CoFe devices with \(B_x = 50\) mT for Pt/CoFe and 10 mT for Ta/CoFe. For each point, a 250 ms current pulse was injected, then \(m_z\) was measured from the anomalous Hall effect (AHE) voltage using a 400 Hz low-amplitude (\(\sim 10^9\) A/m²) AC sense current and a lock-in

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occurs. For Ta/CoFe, by contrast, only a single threshold is observed (Fig. 2(f)), and intermediate states are absent.

To understand this behavior, we employ a micromagnetic model that solves the Landau-Lifshitz-Gilbert equation

\[
\frac{dm}{dt} = -\gamma m \times B_{\text{eff}} + \alpha m \times \frac{dm}{dt} + \gamma B_{\text{SL}} m \\
\times \left( m \times \left( \hat{z} \times \hat{j} \right) \right) - \gamma B_{\text{FL}} m \times \left( \hat{z} \times \hat{j} \right),
\]

with \( \gamma = 1.76 \times 10^{11} \text{s}^{-1} \text{T}^{-1} \) the electron gyromagnetic ratio, \( \alpha \) the Gilbert damping constant, \( \hat{J} \) a unit vector along the current, and \( B_{\text{eff}} \) the effective magnetic field, which includes the external, exchange, anisotropy, demagnetizing, DMI, and thermal fields. The last two terms in (1) represent, respectively, the Slonczewski-like and field-like SOTs, with amplitudes \( B_{\text{SL}} \) and \( B_{\text{FL}} \) proportional to the current density. The DMI effective field is given by

\[
B_{\text{DMI}} = -\frac{2D}{M_S} \left[ (\nabla \cdot m) \hat{z} - \nabla m_z \right].
\]

with \( D \) the DMI constant. Note this expression only holds true at the interface, so it is applicable to thin films. Appropriate boundary conditions were imposed to simulate the DMI.

Simulation parameters correspond to the experimental sample dimensions \( 15000 \times 1200 \times 0.6 \text{ nm} \), Gilbert damping constant \( \alpha = 0.3 \), saturation magnetization \( M_S = 8.3 \times 10^5 \text{A/m} \), uniaxial out of plane anisotropy constant \( K_U = 4.8 \times 10^5 \text{J/m}^3 \), and exchange constant \( A = 1.6 \times 10^{-11} \text{J/m} \). The SHE angle and DMI constants are, respectively, taken from Refs. 5 and 25 as \( \theta_{\text{SH}} = 0.07 \) and \( D = -1.2 \times 10^{-7} \text{J/m}^2 \) for Pt/CoFe, and \( \theta_{\text{SH}} = -0.25 \) and \( D = -0.05 \times 10^{-3} \text{J/m}^2 \) for Ta/CoFe. \( B_{\text{SL}} \) is computed as arising purely from the SHE via \( B_{\text{SL}} = \frac{k_{\text{B}} T_{\text{SH}}}{\hbar} \), with \( e \) the electron charge, \( \hbar \) Planck’s constant, and \( t \) the sample thickness. Unless specified otherwise, all simulations are performed at \( T = 300 \text{ K} \). Simulations were performed with GMultiplet, a graphics processing unit (GPU)-based parallelized commercial code, using a sixth-order Runge-Kutta method with \( 5 \times 5 \times 0.6 \text{ nm} \) discretization and a 1 ps computational time step.

Our first simulations aim to give insight into the influence of thermal fluctuations and DMI on switching dynamics. Here, we apply a continuously swept current at a ramp rate of \( 4 \times 10^{10} \text{ A/m}^2/\text{ns} \). With \( D = T = 0 \), we observe clean switching in which the magnetization remains uniform except for the effect of the demagnetizing field near the edges. In this case, a macrospin model suffices to reproduce the hysteresis loop precisely. As expected, increasing \( T \) yields a narrowing of the hysteresis loop (Fig. 3(a)). In this case, switching takes place via random nucleation of bubbles which expand throughout the whole sample (Fig. 3(c)), as described previously. This non-uniform switching has, however, very little impact on the averaged \( m_z \), yielding no remarkable effects aside from a decrease in the switching current.

When DMI is introduced, the magnetic switching becomes more irregular (i.e., the bubbles are distorted and expand non-isotropically) but the switching current and the averaged \( m_t \) are barely affected for weak DMI (Fig. 3(b)). However, above a threshold DMI constant, which we find to be between 1 and 1.5 times \( \sqrt{AK_U} \) (in agreement with Ref. 28), the DMI is strong enough to promote non-uniform magnetization patterns. In particular, starting from a uniform state at zero current, and increasing the current, we observe the generation of a stripe-like structure, which breaks into a deformed skyrmion lattice, eventually disappearing for high enough currents; this effect is the responsible for the “tails” in the hysteresis loops in Fig. 3(b). Finally, we find that the switching current decreases with decreasing current ramp rate.

We next seek to reproduce micromagnetically the pulsed switching behavior in Figs. 1(c) and 1(d), considering 50 ns long pulses with 1 ns rise and fall times. In the Pt/CoFe sample simulations (Fig. 4(a)), we found that the switching is indeed not deterministic, and it starts via random nucleation of deformed skyrmions or random magnetization reversal on the edges of the sample. If the nucleation occurs within the intermediate switching region, the current intensity is insufficient to make this state vanish, and the non-uniformities spread throughout the sample. This is the cause of the intermediate states observed in Fig. 4(a) (red dashed circles); for larger currents, the probability of non-uniform state generation is higher and the magnetization eventually switches during the pulse application, but it does not reach a fully uniform state. After the pulse is turned off, the non-uniformities spread, giving rise to the stabilization of these intermediate states. In this case, we observe a metastable helical magnetization configuration (Fig. 4(c)) in the form of stripe-like domains separated by left-handed Néel type DWs, as expected for strong DMI. The periodicity of the helix is \~{200} nm, in agreement with the theoretical value.
depending on the sign of the current. Still, the magnetization reverses back to the uniform state, either “up” or “down” during the pulse, but after the pulse, the magnetization precesses to an intermediate state (Fig. 4(a), black circle), which reverts back to the uniform state after the application of a subsequent current pulse of sufficiently large intensity and length.

For the Ta/CoFe samples, experiments reveal a switching current density that is lower than for Pt/CoFe by a factor of ~10. This cannot be explained alone by the higher spin-Hall angle in Ta nor can be attributed to the DMI, which is much weaker in Ta/CoFe than in Pt/CoFe.25 Moreover, the anisotropy field and coercivity are nearly the same for these two samples. The explanation of this lower switching current threshold is instead the presence of a strong current induced field-like SOT, measured in Ref.5 to be $B_{\text{FL}} \approx 0.4 \text{T per } 10^{12} \text{A/m}^2$, which is a factor of ~20 times larger than was measured for Pt/CoFe. In order to quantitatively reproduce the observed switching current values in our simulations, we consider a larger $B_{\text{FL}} \approx 2.5 \text{T per } 10^{12} \text{A/m}^2$. Including this large field-like torque in the simulations leads the magnetization into the direction perpendicular to the injected current during the pulse, but after the pulse, the magnetization precesses back to the uniform state, either “up” or “down” depending on the sign of the current.

The simulations for the Ta/CoFe sample (Fig. 4(b)) agree well with the experimental results. A remarkable aspect of the results in Fig. 4(b) is the absence of stable intermediate states in the magnetization due to the much lower DMI.25 In this case, the macrospin model perfectly reproduces micromagnetic results. Equally remarkable is the influence of the strong field-like SOT on the dynamical switching process; in its presence, the nonuniform bubble domain nucleation observed in Fig. 3(c) is suppressed. In contrast to the case of the Slonczewski-like torque alone, here the magnetization switches in a quasi-uniform manner during the pulse without the formation of transient bubble states.

It is clear from this analysis that the switching process has a crucial stochastic component. The thermal agitation favors the nucleation of bubbles, which is greatly intensified when non-uniform magnetization is promoted by the DMI and which can be suppressed by a strong field-like SOT. We can naively describe our sample as a tristable system; there are three possible states, “up,” “down,” and “intermediate.” The DMI and exchange strength determine whether the “intermediate” state is actually a metastable state or not, as well as the height of the energy barrier between this state and the uniform ones. The applied current modifies the energy barriers between the states via the Slonczewski-like torque, and the thermal agitation is responsible for jumps over these barriers (i.e., early switching processes).

In summary, we have experimentally studied SOT switching of heavy-metal/ferromagnet/oxide trilayers and evaluated micromagnetically the influence of the DMI and field-like SOT. Both experiments and simulations reveal the presence of intermediate states in current-pulse-induced switching in Pt/CoFe, while hysteresis loops in Ta/CoFe are sharp. In addition, simulations show the magnetic configuration of these intermediate states is helical, demonstrating the crucial role of the DMI in their stabilization. Macrospin simulations satisfactorily reproduce the switching characteristics in the absence of DMI, but a micromagnetic approach is required to fully understand the processes that take place during the switching. Although the understanding of current-induced magnetization dynamics in these materials is still in its early stages, our results point out the possibility of stabilizing complex magnetization patterns, such as helices or skyrmions which present promising perspectives for high-performance spintronics applications.

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Applying a current pulse of magnitude close to the switching current density sometimes results in the appearance of two or more domains in the magnetization. However, unlike the intermediate states in Pt/CoFe, which are stable, these configurations always vanish to a uniform state after a time of the order of 1 μs.